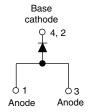


Vishay Semiconductors

Schottky Rectifier, 5.5 A





D-PAK	(TO-252AA)	
D . A	(10 202777)	

PRODUCT SUMMARY				
Package	D-PAK (TO-252AA)			
I _{F(AV)}	5.5 A			
V_{R}	30 V			
V _F at I _F	See Electrical table			
I _{RM}	58 mA at 125 °C			
T _J max.	150 °C			
Diode variation	Single die			
E _{AS}	10 mJ			

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

DESCRIPTION

The VS-50WQ03FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Rectangular waveform	5.5	A				
V _{RRM}		30	V				
I _{FSM}	t _p = 5 µs sine	320	A				
V _F	5 Apk, T _J = 125 °C	0.35	V				
TJ	Range	- 40 to 150	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-50WQ03FNPbF UNITS						
Maximum DC reverse voltage	V_{R}	30	V			
Maximum working peak reverse voltage	V_{RWM}	30				

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDI	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 136 °C	5.5	Α		
Maximum peak one cycle non-repetitive surge current See fig. 7	I	5 μs sine or 3 μs rect. pulse Following any rated load condition and with	320	Α		
	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	130		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 2 A, L = 5 mH		10	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximum	2.0	Α		

VS-50WQ03FNPbF

Vishay Semiconductors

Schottky Rectifier, 5.5 A



Document Number: 94232

Revision: 14-Jan-11

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			
		5 A	T _{.1} = 25 °C	0.46		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	1]=25 0	0.53	V	
See fig. 1	V FM (*)	" 5 A	T _{.1} = 125 °C	0.35		
		10 A	1J = 125 C	0.46		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 25 ^{\circ}\text{C}$ $V_B = \text{Rated } V_B$		3	mA	
See fig. 2	'RM`'	T _J = 125 °C	VR = Nated VR	58	ША	
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum	T T		V	
Forward slope resistance	r _t	ıj = ıj maximum		22.22	mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	590	pF		
Typical series inductance	L _S	Measured lead to lead 5 n	nm from package body	5.0	nH	

Note

 $^{^{(1)}}$ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	3.0	°C/W			
Approximate weight			0.3	g			
Approximate weight			0.01	oz.			
Marking device		Case style D-PAK (similar to TO-252AA)	50WC	03FN			

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



Schottky Rectifier, 5.5 A

Vishay Semiconductors

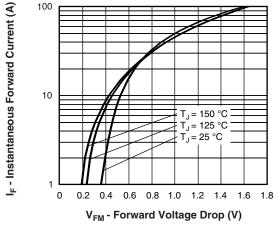


Fig. 1 - Maximum Forward Voltage Drop Characteristics

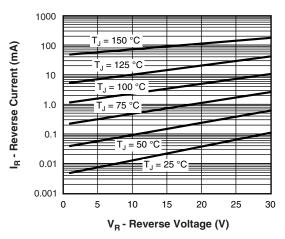


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

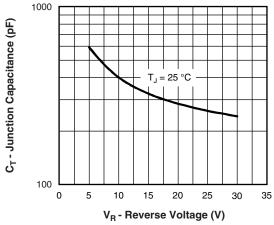


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

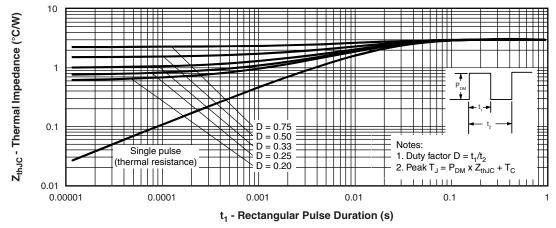


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay Semiconductors

Schottky Rectifier, 5.5 A



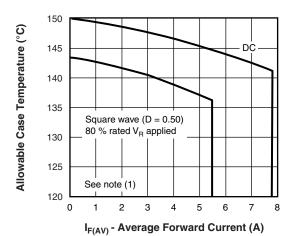


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

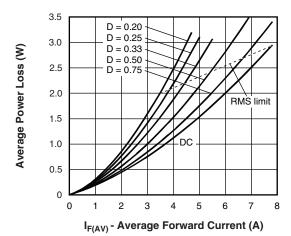
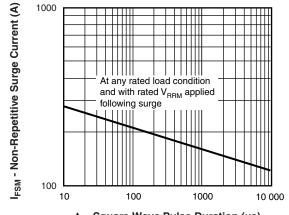


Fig. 6 - Forward Power Loss Characteristics



t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

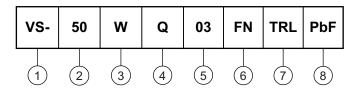


Schottky Rectifier, 5.5 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (5.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (03 = 30 V)

6 - FN = TO-252AA (D-PAK)

7 • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

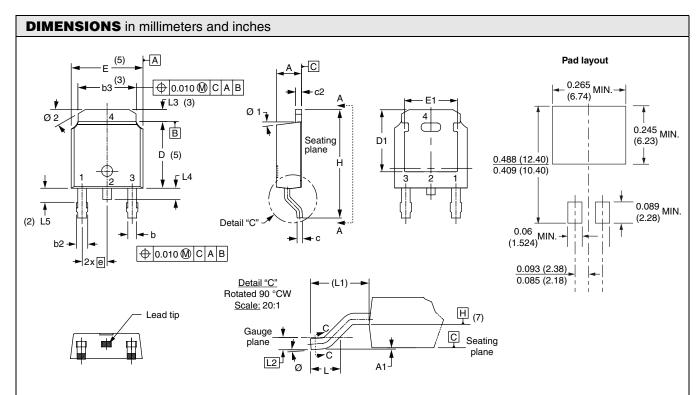
PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95016			
Part marking information	www.vishay.com/doc?95059			
Packaging information	www.vishay.com/doc?95033			
SPICE model	www.vishay.com/doc?95408			



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INCHES MIN. MAX.		NOTES
STWIDOL	MIN.	MAX.			NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIM	ETERS	INCHES		NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74	2.74 BSC		0.108 REF.	
L2	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11